

PATENT APPLICATION

**VOLTAGE TO CURRENT CONVERTER
WITH VARIATION-FREE MOS RESISTOR**

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VOLTAGE TO CURRENT CONVERTER WITH VARIATION-FREE MOS RESISTOR

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BACKGROUND OF THE INVENTION

The present invention relates to current source circuits and, more particularly, to a voltage controlled current source circuit.

Fig. 1 illustrates a conventional voltage controlled current source circuit 100 for generating a current in response to a voltage. Such circuits are also known in the art as voltage-to-current converters. The voltage controlled current source circuit 100 of Fig. 1 includes a transistor 101 and a load impedance 102. The transistor 101 of voltage controlled current source circuit 100 receives a control voltage V_{in} and produces an output current I_o . The transistor 101 may be an NMOS transistor, for example. The current at the output is given by the equation:

$$I_o = \frac{(V_{in} - V_{th})}{R},$$

where I_o is the output current, V_{in} is the control voltage, V_{th} is the threshold voltage of the NMOS transistor, and R is the resistance of the load impedance.

Another conventional voltage controlled current source circuit 200 is shown in Fig. 2. The voltage controlled current source circuit 200 of Fig. 2 includes a transistor 201 and an active load impedance 202. The load impedance used in voltage controlled current source 200 is a NMOS transistor bias in the triode region of operation. The transistor 201 of voltage controlled current source circuit 200 receives a control voltage V_{in} and produces an output current I_o . The transistor 201 may be an NMOS transistor, for example.

One major problem with voltage controlled current sources, such as those in Figs. 1 and 2 is that the load impedance is typically implemented using integrated circuit technology. For example, the resistor in Fig. 1 may be implemented using doped polysilicon, for example. However, typical polysilicon resistors can achieve a tolerance on only about 20% across process. Additionally, process and temperature variations may cause deviations in the circuits of Figs. 1 and 2 by as much as 60%. Accordingly, voltage

controlled current sources utilizing integrated circuit resistors can suffer deviations in the voltage to current relations that are unacceptable in many applications.

Accordingly, a voltage controlled current source that reduces the variation
5 in the voltage to current relationship across process and temperature variations is desired.

SUMMARY OF THE INVENTION

A voltage controlled current source circuit, in accordance with one
embodiment of the present invention, includes a first precision reference current coupled
10 to a voltage control node, a first voltage controlled impedance circuit having a current
input and a first voltage control input, and a first current mirror having a first current
terminal coupled to the current input of the first voltage controlled impedance and a
second current terminal, wherein the first current mirror generates a second reference
current on the second current terminal. The first precision reference current and the
15 second reference current are coupled together at the voltage control node. Additionally,
the first voltage control input is coupled to the voltage control node.

A voltage controlled current source circuit, in accordance with another
embodiment of the present invention, includes a first resistor, a first current mirror having
20 a current terminal coupled to a first terminal of the first resistor, wherein the first current
mirror generates a first reference current, a first voltage controlled impedance circuit
having a current input and a first voltage control input, a second current mirror having a
current terminal coupled to the current input of the voltage controlled impedance, wherein
the second current mirror generates a second reference current. The first reference
25 current and the second reference current are coupled together at a voltage control node
and the first voltage control input is coupled to the voltage control node.

A voltage controlled current source circuit, in accordance with another
embodiment of the present invention, includes a first transistor having a control terminal
30 coupled to a control voltage, a first terminal, and a second terminal, a first resistor, a first
current mirror having a current terminal coupled to a first terminal of the first resistor,
wherein the first current mirror generates a first reference current, a first voltage
controlled impedance circuit having a current input and a first voltage control input, a
second current mirror having a current terminal coupled to the current input of the voltage

controlled impedance, and a second voltage controlled impedance circuit having a current input coupled to the second terminal of the first transistor, and a second voltage control input, wherein the second current mirror generates a second reference current. The first reference current and the second reference current are coupled together at a voltage control node and the first voltage control input is coupled to the voltage control node.

According to one embodiment, the first resistor is an external resistor for generating a reference current.

According to one embodiment, the present invention includes a method of controlling a current. The method comprises generating a first current through a resistor, generating a second current at a current input of a voltage controlled impedance, providing reproductions of the first current and the second current at a voltage control node to generate a first control voltage at the voltage control node, and coupling the first control voltage at the voltage control node to a voltage input of the voltage controlled impedance, wherein the first control voltage corresponds to the difference between the first current and the second current.

The following detailed description and the accompanying drawings provide a better understanding of the nature and advantages of the present invention.

BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 illustrates a contemporary voltage controlled current source circuit for generating a current in response to a voltage.

Fig. 2 illustrates another contemporary voltage controlled current source circuit for generating a current in response to a voltage.

Fig. 3 illustrates a voltage controlled current source circuit according to one embodiment of the present invention.

Fig. 4 illustrates a voltage controlled current source circuit according to another embodiment of the present invention.

Fig. 5 illustrates an exemplary implementation of a voltage controlled current source circuit according to one embodiment of the present invention.

Fig. 6 illustrates another exemplary implementation of a voltage controlled current source circuit according to another embodiment of the present invention.

DESCRIPTION OF THE SPECIFIC EMBODIMENTS

Fig. 3 illustrates a voltage controlled current source circuit according to one embodiment of the present invention. Voltage controlled current source circuit 300 includes a precision reference current source 310, a first current mirror 320, and a voltage controlled impedance 330. The precision reference current source 310 generates a reference current that is coupled to a voltage control node V_c 350. The voltage controlled impedance circuit is coupled between a current input 331 and a reference voltage V_{ref} , and includes a voltage control input 332 for varying the impedance characteristic between the current input and V_{ref} . Accordingly, the impedance of the voltage controlled impedance circuit is dependent upon the voltage at the voltage control input 332. Furthermore, the first current mirror 320 has a first current terminal coupled to current input 331 of the voltage controlled impedance. A second current terminal of the current mirror 320 is coupled to the voltage control node.

In operation, the precision reference current source generates a precision current into or out of voltage control node 350. Additionally, the voltage controlled impedance circuit sets up a current between the current input 331 and the reference voltage V_{ref} . The current mirror 320 provides a reproduction of the current in the voltage controlled impedance circuit. The reproduced current is a second reference current that is driven out of or into the voltage control node 350. The action of the precision reference current and the second reference current from the current mirror 320 act to increase or decrease the voltage at the voltage control node 350. The voltage on the voltage control node 350, in turn, acts to alter the impedance of the voltage controlled impedance circuit 330 such that the current through the voltage controlled impedance circuit 330 is the same as the precision reference current.

Fig. 4 illustrates voltage controlled current source circuit 400 according to another embodiment of the present invention. Voltage controlled current source circuit

400 includes a resistor 410 having a terminal coupled to a first voltage reference V_{ref1} . The resistor may be a high tolerance resistor such as an external 0.01% resistor, for example. The other terminal of resistor 410 is coupled to a current terminal of current mirror 411. The current mirror 411 has a second current terminal coupled to voltage control node 450 for generating a precision reference current into or out of voltage control node 450. Voltage controlled current source circuit 400 also includes a first voltage controlled impedance circuit 430. The first voltage controlled impedance circuit 430 is coupled between a current input 431 and a second voltage reference V_{ref2} . The current input 431 is coupled to a current mirror 420. A first current terminal of the current mirror 420 is coupled to the voltage control node 450 and a second terminal of the current mirror 420 is coupled to the current input of the voltage controlled impedance circuit 430. The voltage control node 450 is coupled to a voltage control input 432 of the first voltage controlled impedance circuit 430.

Additionally, the voltage control node 450 is coupled to a voltage control input 442 of a second voltage controlled impedance circuit 440. The second voltage controlled impedance circuit 440 is coupled between a current input 441 and a third voltage reference V_{ref3} . The current input of the second voltage controlled impedance circuit 440 is coupled to the source of an NMOS transistor 450. The gate of the NMOS transistor 450 is coupled to receive a control voltage V_{in} , and the drain provides a voltage controlled output current I_o . By providing a precision reference current into voltage control node 450, and by adjusting the voltage on voltage control node 450 to ensure that the current through the first voltage controlled impedance circuit 430 matches the precision reference current, the voltage controlled impedance circuits 430 and 440 can thereby be tuned to provide precise voltage to current relationships across process and temperature variations. It is to be understood that in various embodiments of the present invention, the polarity of the precision reference current, the second reference current of the current mirror 420, and the control voltage to impedance relation of the voltage controlled impedance circuits may be altered according to known principles to achieve the features and advantages of the present invention. Such modifications would be within the knowledge of one of ordinary skill in the art in light of the present disclosure. Accordingly, in one embodiment V_{ref1} , V_{ref2} , and V_{ref3} may be at the same potential (e.g. ground potential or zero volts), or alternatively at different potentials from one or more of each other.

Fig. 5 illustrates an exemplary implementation of a voltage controlled current source circuit 500 according to one embodiment of the present invention. Voltage controlled current source circuit 500 includes a resistor 510 coupled between the drain of a PMOS transistor 511 and ground. PMOS transistor 511 has a source coupled to a supply voltage Vdd and a gate coupled to the drain. The gate of PMOS transistor is also coupled to the gate of PMOS transistor 512. The source of PMOS transistor 512 is also coupled to Vdd, and the drain is coupled to a voltage control node 550. Together, PMOS transistor 511, PMOS transistor 512, and resistor 510 form a precision current source for providing a precision reference current I_s into voltage control node 550. Additionally, transistors 511 and 512 form a single stage current mirror as is well known in the art.

Voltage control node 550 is coupled to a voltage control input 532 of an exemplary voltage controlled impedance circuit 530. Voltage controlled impedance circuit 530 includes a first NMOS transistor 534 having a gate coupled to the voltage control node 550. The drain of transistor 534 is coupled to the current input 531 of the voltage controlled impedance circuit 530. The source of transistor 534 is coupled to ground. Voltage controlled impedance circuit 530 also includes a second NMOS transistor 533 having a gate and drain coupled to the current input 531 and a source coupled to ground. The voltage to current relationship of the voltage controlled impedance circuit 530 can be obtained by observing the following:

$$I = \frac{V}{R_{eq}}, \quad (1)$$

$$I_{MN1} = k_1(V_{gs1} - V_{t1})V_{ds1} - \frac{k_1 V_{ds1}^2}{2}, \quad (2)$$

$$I_{MN2} = \frac{k_2}{2}(V_{gs2} - V_{t2})^2. \quad (3)$$

Additionally, the following relations apply:

$$I = I_{MN1} + I_{MN2}, \quad (4)$$

$$V_{ds1} = V_{ds2}, \quad (5)$$

$$V_{ds1} = V_{gs1} + V_{t1}. \quad (6)$$

Therefore, assuming matched devices (i.e. $k_1 = k_2 = k$), the voltage to current relation is given by:

$$I = k(V_{gs1} - V_{t1})V_{ds2}. \quad (7)$$

This corresponds to an equivalent resistance for the voltage controlled impedance circuit given by:

$$R_{eq} = \frac{1}{k(V_c - V_{t1})}, \quad (8)$$

where V_c is the voltage at the voltage control node 530, V_{t1} is the threshold voltage of NMOS transistor 534, and k is a device parameter.

The current I into the current input 531 of voltage controlled impedance circuit 530 is passed through a two-stage current mirror comprised of transistors 520, 521, 522, and 523 to produce a reference current I_R . The reference current I_R and precision reference current I_s act to increase or decrease the voltage at the voltage control node 550. The voltage on voltage control node 550, in turn, acts to alter the impedance of the voltage controlled impedance circuit 530 such that the current through the voltage controlled impedance circuit 530 is the same as the precision reference current I_s .

Fig. 6 illustrates another exemplary implementation of a voltage controlled current source circuit 600 according to one embodiment of the present invention. Voltage controlled current source circuit 600 includes a resistor 610 coupled between the drain of a PMOS transistor 611 and ground. In one embodiment, resistor 610 is an external resistor having a high tolerance. It is to be understood that the tolerance of a resistor is a term to refer to the precision of the resistor. Therefore, a 1 k Ω (i.e. kilo-ohm) resistor having a high tolerance of 0.01%, for example, will have an actual resistor value of 1 k $\Omega \pm 10\Omega$. A first terminal of the resistor 610 is coupled to a reference voltage (e.g. ground). A second terminal of the resistor 610 is coupled to the drain and gate of a PMOS

transistor 611. PMOS transistor 611 has a source coupled to a supply voltage Vdd. Accordingly, a very accurate current I_{ref} may be set up in resistor 610.

The gate of PMOS transistor 611 is also coupled to the gate of PMOS transistor 612. The source of PMOS transistor 612 is coupled to Vdd, and the drain is coupled to a voltage control node 650. Together, PMOS transistor 611 and PMOS transistor 612 form a current mirror to mirror current I_{ref} . A precision current I_s appears at the current output terminal of the current mirror comprised of transistors 611 and 612. It is to be understood that the combination of PMOS transistor 611, PMOS transistor 612, and resistor 610 form a precision current source for providing a precision reference current I_s into voltage control node 650. Accordingly, other forms of process and temperature insensitive precision current sources could also be used. In one embodiment, the W/L (i.e. width to length of the gate) ratio of PMOS transistor 611 to PMOS transistor 612 is M:N. Therefore, according to well known principles, the precision reference current I_s can be scaled.

Voltage control node 650 is coupled to voltage control inputs 632 and 642 of exemplary voltage controlled impedance circuits 630 and 640. Voltage control node 650 is also coupled to a current input 631 of voltage controlled impedance circuit 630 through a two-stage current mirror. A current mirror comprised of PMOS transistor 620 and PMOS transistor 621 includes a first current terminal coupled to the current input 631 of voltage controlled impedance circuit 630. The source of PMOS transistor 620 is coupled to a supply voltage Vdd. The gate and drain of PMOS transistor 620 are coupled together to form the first current terminal of the current mirror. The gate of PMOS transistor 620 is also coupled to the gate of PMOS transistor 621. The source of PMOS transistor 621 is coupled to the supply voltage Vdd, and the drain of PMOS transistor 621 forms the second current terminal of the current mirror.

A current mirror comprised of NMOS transistor 622 and NMOS transistor 623 includes a first current terminal coupled to the drain of PMOS transistor 621. The source of NMOS transistor 622 is coupled to ground. The gate and drain of NMOS transistor 622 are coupled together to form the first current terminal of the current mirror. The gate of NMOS transistor 622 is also coupled to the gate of NMOS transistor 623. The source of NMOS transistor 623 is coupled to the ground. The drain of NMOS

transistor 623 forms the second current terminal of the current mirror, and is coupled to the voltage control node 650.

5 The voltage controlled impedance 630 has a current input 631 coupled to the voltage control node 650 through the two-stage current mirror and a voltage control input coupled to receive a voltage from the voltage control node. The voltage controlled impedance includes a first NMOS transistor 634 having a gate coupled to the voltage control node 650. The drain of transistor 634 is coupled to the current input 631 of the voltage controlled impedance circuit 630. The source of transistor 634 is coupled to ground. Voltage controlled impedance circuit 630 also includes a second NMOS transistor 633 having a gate and drain coupled to the current input 631 and a source coupled to ground.

15 The voltage controlled impedance 630 will generate a current I . This current will be reproduced at the voltage control node 630 by the action of the two-stage current mirror comprised of PMOS transistors 620 and 621 and NMOS transistors 622 and 623. Additionally, resistor 610 will generate a current I_{ref} . I_{ref} will be reproduced at the voltage control node 630 by the action of the current mirror comprised of PMOS transistors 611 and 612. As a result, two reference currents will act to change the voltage on the voltage control node 650, and the voltage on the voltage control node 650 is used to adjust the current I to be equal to the current through the resistor. For example, if I is greater than I_{ref} , then I_R is greater than I_s , and the voltage on the voltage control node 650 will decrease. However, as the voltage at node 650 decreases, the gate voltage on NMOS transistor decreases and the current I begins to decrease. On the other hand, if I_{ref} is greater than I , then I_s is greater than I_R , and the voltage on the voltage control node 650 will increase. However, as the voltage at node 650 increases, the gate voltage on NMOS transistor increases and the current I begins to increase. As a result, the impedance of the voltage controlled impedance 630 will be determined by the value of the reference current I_s . For the voltage controlled current source circuit 600, the reference current is set by resistor 610, and the impedance of the voltage controlled impedance 630 will be equal to the resistance of resistor 610.

In one embodiment, one or more of transistors pairs 611 and 612, 620 and 621, and/or 622 and 623 may have scaled W/L ratios to change the relation between the

reference current I_s and the impedance of the voltage controlled impedance 630. For example, if transistors 611 and 612 are scaled 1:2 respectively, then I_s is twice the value I_{ref} . Therefore, I will be twice the value of I_{ref} and the impedance of the voltage controlled impedance circuit 630 will be one-half the value of resistor 610. On the other hand, if

5 transistors 620 and 621, or transistors 622 and 623, are scaled 1:2 respectively, then I_R is twice the value I . Therefore, I will be one-half the value of I_{ref} and the impedance of the voltage controlled impedance circuit 630 will be twice the value of resistor 610. Of course, other scaling combinations could be used to adjust the impedance of the voltage controlled impedance circuit 630 in light of the above description.

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The voltage at the voltage control node 650 of voltage controlled current source 600 can also be used to establish currents in other portions of an electronic system. For example, voltage controlled current source 600 also includes a second voltage controlled impedance circuit 640. As illustrated in equation (8) above, the equivalent

15 resistance R_{eq} of voltage controlled impedance circuits 630 and 640 of the present embodiment are independent of the voltage at the current inputs 631 and 641, and dependent upon the voltage at the voltage control inputs 632 and 642. Therefore, reference current I_s can be set to establish the requisite voltage on node 650 for the desired equivalent resistance for the voltage controlled impedance 630, and the voltage on

20 node 650 can be used to control the equivalent resistance of other voltage controlled impedance circuits (e.g. circuit 640) in other portions of the circuit.

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For example, voltage controlled impedance circuit 640 includes an NMOS transistor 644 having a gate coupled to the voltage control node 650 for controlling the

25 equivalent resistance between the current input 641 and ground. NMOS transistor has a drain coupled to the current input 641 and a source coupled to ground. A second NMOS transistor 643 has a source coupled to the source of NMOS transistor 644. The gate and drain of NMOS transistor 644 are coupled to the drain of NMOS transistor 643. NMOS transistor 650 has a source coupled to the current input 641 of the voltage controlled

30 impedance 640 and a drain coupled to some other portion of the system. The gate of NMOS transistor 650 receives a control voltage V_{in} for controlling the current I_o at the drain. For the present embodiment, the equivalent resistance of the voltage controlled impedance 640 is equal to the resistance of resistor 610 (i.e. R_{ext}). Therefore, the current I_o at the drain of transistor 650 is given as follows:

$$I_o = \frac{V_{in} - V_t}{R_{ext}}. \quad (9)$$

Having fully described alternative embodiments of the present invention,
 5 other equivalent or alternative techniques according to the present invention will be
 apparent to those skilled in the art. For example, while the present invention was
 primarily described in connection with a PMOS current mirrors and NMOS voltage
 controlled impedance circuits, opposite polarity devices could also be used. These
 equivalents and alternatives along with the understood obvious changes and modifications
 10 are intended to be included within the scope of the present invention as defined by the
 following claims.